

Vishay Semiconductors

Small Signal Schottky Diode



FEATURES

Integrated protection ring against static discharge



 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912







LINKS TO ADDITIONAL RESOURCES



MECHANICAL DATA

Case: MicroMELF
Weight: approx. 12 mg
Cathode band color: black
Packaging codes/options:

TR3/10K per 13" reel (8 mm tape), 10K/box TR/2.5K per 7" reel (8 mm tape), 12.5K/box

APPLICATIONS

• Applications where a very low forward voltage is required

PARTS TABLE						
PART	TYPE DIFFERENTIATION	ORDERING CODE	CIRCUIT CONFIGURATION	REMARKS		
BAS385	V _R = 30 V	BAS385-TR3 or BAS385-TR	Single	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	30	V	
Peak forward surge current	t _p = 10 ms	I _{FSM}	5	Α	
Repetitive peak forward current	t _p ≤ 1 s	I _{FRM}	300	mA	
Forward continuous current		I _F	200	mA	
Average forward current	V _{RWM} = 25 V	I _{FAV}	200	mA	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	320	K/W		
Junction temperature		Tj	125	°C		
Storage temperature range		T _{stg}	-65 to +150	°C		

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 0.1 \text{mA}$	V _F			240	mV
	I _F = 1 mA	V _F			320	mV
Forward voltage	I _F = 10 mA	V _F			400	mV
	I _F = 30 mA	V _F			500	mV
	I _F = 100 mA	V _F			800	mV
Reserve current	$V_R = 25 \text{ V}, t_p = 300 \mu\text{s}$	I _R			2.3	μA
Diode capacitance	$V_R = 1 V, f = 1 MHz$	C _D			10	pF

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

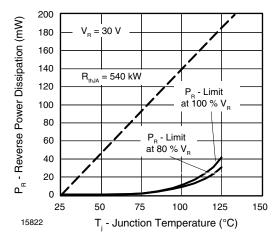


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

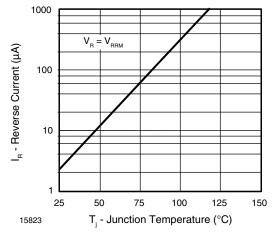


Fig. 2 - Reverse Current vs. Junction Temperature

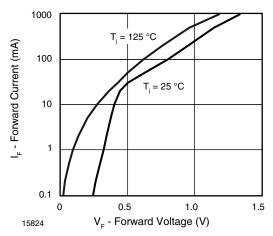


Fig. 3 - Forward Current vs. Forward Voltage

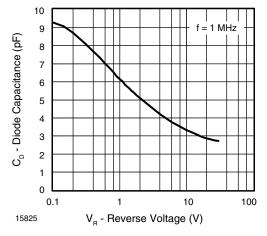
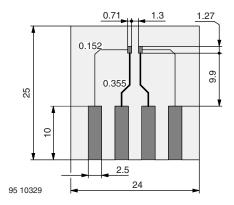


Fig. 4 - Diode Capacitance vs. Reverse Voltage

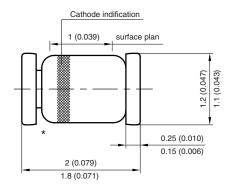


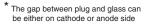
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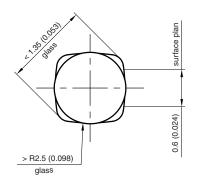
Fig. 5 - Board for R_{thJA} Definition (in mm)



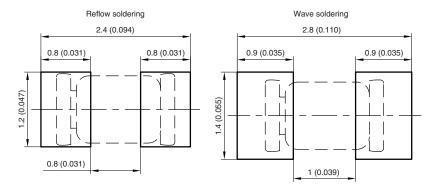
PACKAGE DIMENSIONS in millimeters (inches): MicroMELF







Foot print recommendation:



Created - Date: 26.July.1996 Rev. 13 - Date: 07.June.2006 Document no.:6.560-5007.01-4 96 12072



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